## Sheet 1 of 1 Docket Number 204552028600 Application Number 10/601,755 Form PTO-1449 Applicant INFORMATION DISCLOSURE CITATION Takahisa KURAHASHI et al. IN AN APPLICATION Group Art Unit 2811 OIPE (Use several sheets if necessary) Filing Date June 24, 2003 Mailing Date October 23, 2003 OCT 2 4 2003 U.S. PATENT DOCUMENTS Filing Date If Class **Subclass** Date Document No. Name Examiner Ref. Appropriate **Initials** No. Kurahashi et al. 5/24/2002 1. 12/12/2002 2002/0185653 DAK FOREIGN PATENT DOCUMENTS **Translation** Subclass Document No. Country Class Examiner Ref. Date YES NO **Initials** No. Abstract DAL JP 2001-68727 Japan 2. 3/16/2001 Abstract JP 2001-68732 3. 3/16/2001 Japan Abstract 3/15/2002 JP 2002-076433 Japan 4. Abstract 4/25/2003 JP 2003-124508 Japan 5. Abstract 7/25/2003 JP 2003-209282 Japan OTHER DOCUMENTS (including author, title, Date, Pertinent Pages, Etc.) Title Ref. Examiner **Initials** No. Streubel et al. "High Brightness Visible (660 nm) Resonant-Cavity Light-Emitting Diode" 7. om IEEE Photonics Technology Letters, Vol. 10, No. 12, 12/1998, pp. 1685-1687. DATE CONSIDERED: **EXAMINER:** Kong, Donghae

EXAMINER: Initial if citation considered, whether or not the citation conforms with MPEP 609. Draw a line through the citation if not in conformance and not considered. Include a copy of this form with next communication to applicant.